

# ZK1000A/2000V

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## HIGH POWER FAST RECOVERY RECTIFIER

### Features:

- . All Diffused Structure
- . Fast Switching Performance
- . Soft Reverse Recovery
- . Rugged Ceramic Hermetic Package
- . Pressure Assembled Device

### ELECTRICAL CHARACTERISTICS AND RATINGS

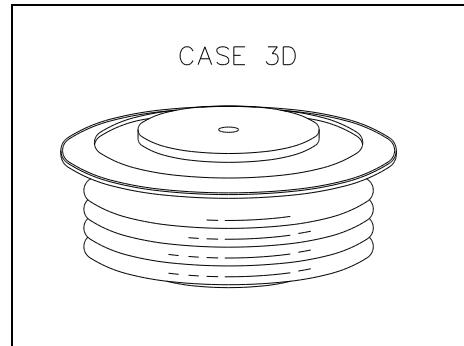
#### Reverse Blocking

Device Type	$V_{RRM}$ (1)	$V_{RSM}$ (1)
ZK1000A	2000	2100

$V_{RRM}$  = Repetitive peak reverse voltage

$V_{RSM}$  = Non repetitive peak reverse voltage (2)

Repetitive peak reverse leakage	$I_{RRM}$	10 mA 40 mA (3)
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#### Notes:

All ratings are specified for  $T_j=25^\circ\text{C}$  unless otherwise stated.

(1) All voltage ratings are specified for an applied 50Hz/60Hz sinusoidal waveform over the temperature range  $-40$  to  $+125^\circ\text{C}$ .

(2) 10 msec. max. pulse width

(3) Maximum value for  $T_j = 125^\circ\text{C}$ .

(4) See parameter definition below :

#### Conducting - on state

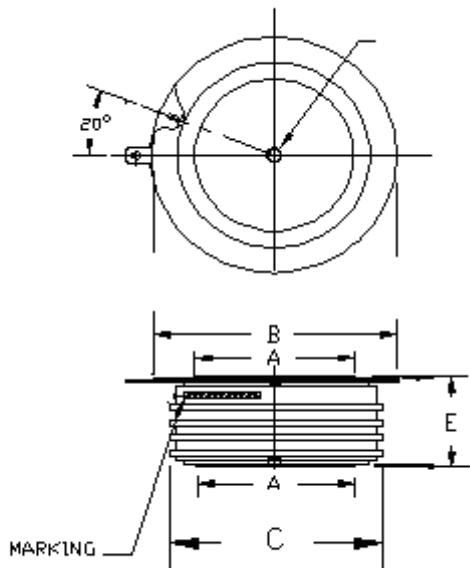
Parameter	Symbol	Min.	Max.	Typ	Units	Conditions
Average value of on-state current	$I_{F(AV)}$		1000		A	Sinewave, $180^\circ$ conduction, $T_c = 78^\circ\text{C}$
RMS value of on-state current	$I_{FRMS}$		2000		A	Nominal value
Peak one cycle surge (non repetitive) current	$I_{FSM}$		15000 13000		A A	8.3 msec (60Hz), sinusoidal wave-shape, $180^\circ$ conduction, $T_j = 125^\circ\text{C}$ 10.0 msec (50Hz), sinusoidal wave-shape, $180^\circ$ conduction, $T_j = 125^\circ\text{C}$
$I^2t$	$I^2t$		1050000		$\text{A}^2\text{s}$	8.3 msec and 10.0 msec
Peak on-state voltage	$V_{FM}$		2.30		V	$I_{FM} = 3140 \text{ A}$ ; Duty cycle $\leq 0.01\%$ ; $T_j$ max
Reverse Recovery Current (4)	$I_{RM(REC)}$				A	$I_{FM} = 1000 \text{ A}$ ; $dI_F/dt = 25 \text{ A}/\mu\text{s}$ ; $T_j$ max
Reverse Recovery Charge (4)	$Q_{rr}$		*	200	$\mu\text{C}$	$I_{FM} = 1000 \text{ A}$ ; $dI_F/dt = 25 \text{ A}/\mu\text{s}$ ; $T_j$ max
Reverse Recovery Time (4)	$t_{RR}$		4		$\mu\text{s}$	

\* For guaranteed maximum values, contact factory

Parameter	Symb ol	Min.	Max.	Typ.	Units	Conditions
Operating temperature	T <sub>j</sub>	-40	+125		°C	
Storage temperature	T <sub>stg</sub>	-40	+125		°C	
Thermal resistance - junction to case	R <sub>θ (j-c)</sub>		0.043 0.086		°C/W	Double sided cooled Single sided cooled
Thermal resistance - case to sink	R <sub>θ (c-s)</sub>		.015 .030		°C/W	Double sided cooled * Single sided cooled *
Mounting force	F	13.5	16.5		kN	

\* Mounting surfaces smooth, flat and greased

## CASE OUTLINE AND DIMENSIONS



A: 34 mm

B: 58 mm

C: 53 mm

E: 26 mm